

HOLTEK



HT82V733

240mA Audio Power Amp

Features

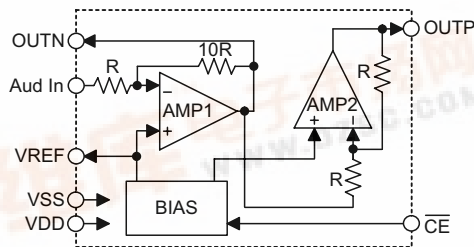
- High signal-to-noise ratio
- High slew rate
- Low distortion
- Large output voltage swing
- Excellent power supply ripple rejection
- Low power consumption
- Short-circuit elimination
- Wide temperature operating range
- No switch ON/OFF clicks
- Low standby current
- Power off control
- Direct drive speaker
- 8-pin SOP package

General Description

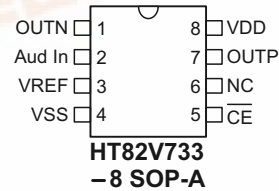
HT82V733 is an integrated class AB mono speaker driver contained in an SOP-8 package. The device is

fabricated in a CMOS process and has been primarily developed for portable digital audio applications.

Block Diagram



Pin Assignment



Pin Description

Pin No.	Pin Name	I/O	Description
1	OUTN	O	Negative output
2	Aud In	I	Audio input
3	VREF	O	Speaker non-inverting input voltage reference
4	VSS	—	Negative power supply, ground
5	CE	I	Chip enable, low active
6	NC	—	Not connected
7	OUTP	O	Positive output
8	VDD	—	Positive power supply

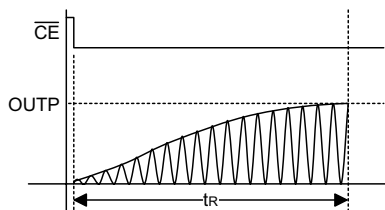
Electrical Characteristics
 $V_{SS}=0V$, $T_a=25^{\circ}C$

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V _{DD}	Conditions				
Supplies							
V _{DD}	Supply Voltage	—	—	2.4	5.0	6.0	V
V _{SS}	Negative Supply Voltage	5V	—	—	0	—	V
I _{STB}	Standby Current	—	—	—	—	1	μA
I _{DD}	Operating Current	—	V _I =0, No load	2	4	10	mA
			V _{P-P} =500mV, f _I =1kHz No load	4.8	12.3	23.5	
P _{tot}	Total Power Dissipation	—	V _{P-P} =500mV, f _I =1kHz No load	15	60	140	mW
DC Characteristics							
V _{I(OS)}	Input Offset Voltage	5V	—	—	12	—	mV
		3V		—	2.5	—	
I _O	Maximum Output Current (THD+N)/S<1%	5V	Current	—	240	—	mA
		3V	Current	—	160	—	
V _O	Output Voltage Swing (THD+N)/S<1%	5V	R _L =16Ω	1.2	—	4	V
			R _L =8Ω	1.8	—	3.4	
			R _L =4Ω	2.1	—	3	
		3V	R _L =16Ω	0.6	—	2.3	V
			R _L =8Ω	0.9	—	1.9	
			R _L =4Ω	1.1	—	1.7	
PSRR	Power Supply Rejection Ratio	5V	f _I =100Hz; V _{ripple(p-p)} =100mV	—	71	—	dB
		3V		—	62	—	
AC Characteristics							
(THD+N)/S	Total Harmonic Distortion Plus Noise-to-signal Ratio	5V	V _{O(p-p)} =3.5V R _L =8Ω	—	−48	—	dB
				—	3	—	%
		3V	V _{O(p-p)} =1.5V R _L =8Ω	—	−30	—	dB
				—	3	—	%
S/N	Signal-to-noise Ratio	5V	—	—	60	—	dB
		3V		—	58	—	

Functional Description

OUTP rising time (t_R)

When \overline{CE} active low, the HT82V733 need rising time to output fully on OUTP pin. However, the rising time depends on C1. (*see the application circuits)

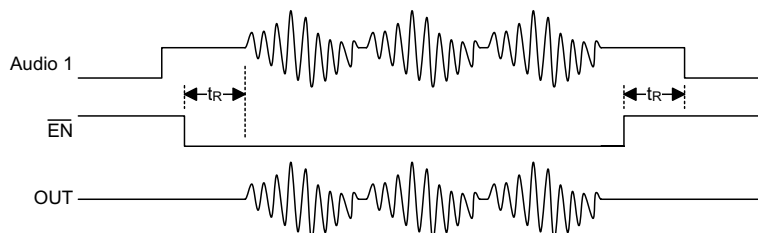


Capacitor t_R Voltage	0.1 μ F	1 μ F	4.7 μ F	10 μ F
2.2V	15ms	30ms	90ms	185ms
3V	15ms	30ms	90ms	185ms
4V	15ms	30ms	90ms	185ms

For battery based applications, power consumption is a key issue, therefore the amplifier should be turned off when in the standby state. In order to eliminate any speaker sound bursts while turning the amplifier on, the application circuit, which will incorporate a capacitance value of C1, should be adjusted in accordance with the speaker's audio frequency response. A greater value of C1 will improve the noise burst while turning on the amplifier. The recommended operation sequence is:

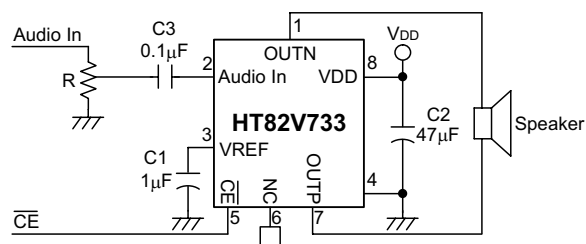
Turn On: audio1 signal standby (1/2 VDD) \rightarrow enable amplifier \rightarrow wait t_R for amplifier ready \rightarrow audio1 output

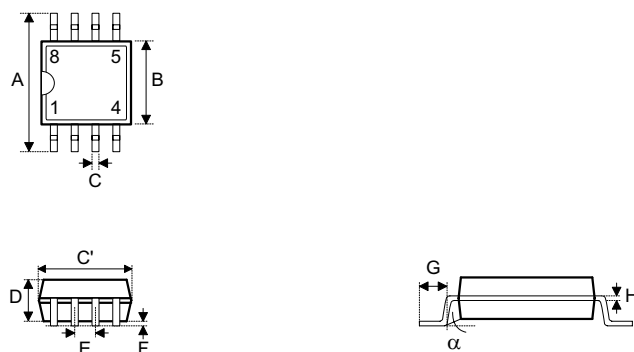
Turn Off: audio1 signal finished \rightarrow disable amplifier \rightarrow wait t_R for amplifier off \rightarrow audio1 signal off



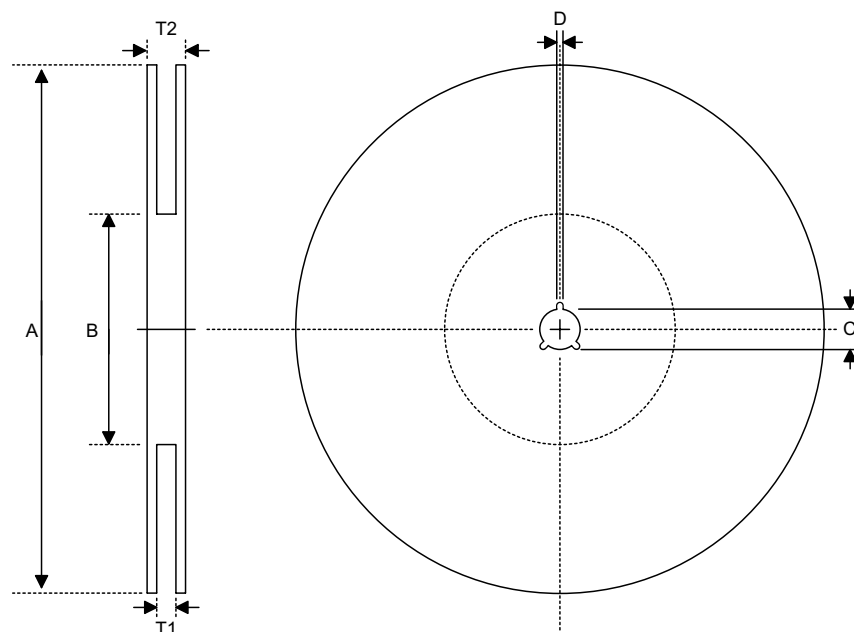
If the application is not powered by batteries and there is no problem with amplifier On/Off issue, a capacitor value of 0.1 μ F for C1 is recommended.

Application Circuits



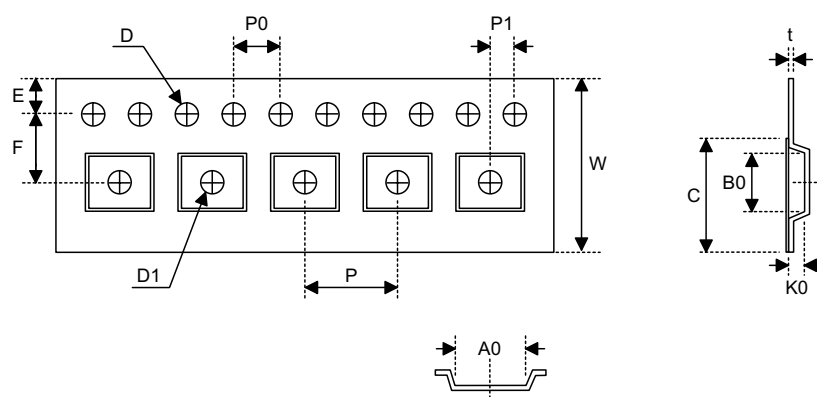
Package Information
8-pin SOP (150mil) outline dimensions


Symbol	Dimensions in mil		
	Min.	Nom.	Max.
A	228	—	244
B	149	—	157
C	14	—	20
C'	189	—	197
D	53	—	69
E	—	50	—
F	4	—	10
G	22	—	28
H	4	—	12
α	0°	—	10°

Product Tape and Reel Specifications
Reel dimensions


SOP 8N

Symbol	Description	Dimensions in mm
A	Reel Outer Diameter	330±1.0
B	Reel Inner Diameter	62±1.5
C	Spindle Hole Diameter	13.0+0.5 -0.2
D	Key Slit Width	2.0±0.15
T1	Space Between Flange	12.8+0.3 -0.2
T2	Reel Thickness	18.2±0.2

Carrier tape dimensions

SOP 8N

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	12.0+0.3 -0.1
P	Cavity Pitch	8.0±0.1
E	Perforation Position	1.75±0.1
F	Cavity to Perforation (Width Direction)	5.5±0.1
D	Perforation Diameter	1.55±0.1
D1	Cavity Hole Diameter	1.5+0.25
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	6.4±0.1
B0	Cavity Width	5.20±0.1
K0	Cavity Depth	2.1±0.1
t	Carrier Tape Thickness	0.3±0.05
C	Cover Tape Width	9.3

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